

IMOTION™ IMM101T/IMM102T - Smart IPM for motor controlFully integrated high-performance turnkey motor control system

Quality requirement category: Industry

IMM101T/IMM102T series is a family of fully-integrated, turnkey high-voltage Motor Drive Module designed for high-performance, high-efficiency PMSM/BLDC motor drive applications such as fans, pumps and compressors. It integrates Infineon's Advanced Motion Control Engine (MCE), gate driver and six power MOSFETs in a single 12x12mm package.

Feature list

- Motion control engine (MCE) as ready-to-use controller solution for variable speed drives
- Field oriented control (FOC) for permanent magnet synchronous motor (PMSM)
- Space vector PWM with sinusoidal commutation and integrated protection features
- Current sensing via single or leg shunt through direct interface
- Sensorless operation
- Integrated analog comparators for over-current protection
- Built-in temperature sensor
- 3.3V or 5.0V supply voltage options for controller
- 15V supply voltage for gate driver
- 3 different power MOSFET options: $6\Omega/500V$, $1.4\Omega/650V$ and $0.95\Omega/650V$
- Integrated bootstrap FET
- Support for hall sensors
- Boost PFC control (IMM102T only)
- Flexible host interface options for speed commands: UART, PWM or analog signal
- Support for IEC 60335 ('Class B')
- Isolation 1500V_{RMS} 1min
- Very compact 12x12mm PQFN package

Applications

- Fans
- Pumps
- Compressors



IMM100 series description

IMM101T/IMM102T devices belong to IMM100 series of iMOTION™ Smart IPMs. IMM100 series is a family of fully-integrated, programmable or configurable ("turnkey") high-voltage Motor Drive Modules designed for high-performance, high-efficiency PMSM (BLDC) motor drive applications such as fans, pumps and compressors. It integrates a controller, a gate driver and six power MOSFETs. IMM100 series is available in two variants: "A"-variant and "T"-variant. "A"-variant (IMM100A-xxx) includes a fully programmable ARM® Cortex®-M0 controller, while "T"-variant (IMM10xT-xxx) features the Infineon's patented Motion Control Engine (MCE).

Both variants offer different control configuration options for PMSM motor-drive system in a compact 12x12mm surface-mount package which minimizes external components count and PCB area. This thermally enhanced package provides excellent thermal performance working with or without heatsink. The package features a 1.3mm creepage distance between the high-voltage pads beneath the package to ease the surface mounting with standard SMT process and increase the robustness of the system.

IMM100 series integrates either 500V FredFET or 650V CoolMOS and the industry benchmark 3-phase high-voltage, rugged gate driver with integrated bootstrap functionality. Depending on the power MOSFETs employed in the package, IMM100 series covers applications with a rated output power from 25W to 80W with 500V/600V maximum DC voltage. In the 600V versions, the Power MOS technology is rated 650V, while the gate driver is rated 600V, which determines the maximum allowable DC voltage of the system.

Ordering information

IMM100T devices integrate an MCE for the control of variable speed drives. By integrating both the required hardware and software to perform control of a permanent magnet synchronous motor (PMSM) they provide the shortest time to market for any motor system at the lowest system and development cost.

Product type	Application	Output Rating	R _{DS(ON)} Typ
IMM101T-015M	Single Motor Control	500V / 1A	4.8 Ω
IMM101T-046M	Single Motor Control	600V / 4A	1.26 Ω
IMM101T-056M	Single Motor Control	600V / 4A (optimized for low-frequency operation)	0.86 Ω
IMM102T-015M	Single Motor Control + Boost PFC	500V / 1A	4.8 Ω
IMM102T-046M	Single Motor Control + Boost PFC	600V / 4A	1.26 Ω
IMM102T-056M	Single Motor Control + Boost PFC	600V / 4A (optimized for low-frequency operation)	0.86 Ω

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1 Overview

IMM100T modules contain a processor core that can address the real-time control needs of motor control. It can use low-cost single shunt or leg shunts as motor current feedback by a combination of on-chip hardware and firmware. Complex FOC control algorithms either sensorless or with sensors, as well as system level control can be easily implemented inside IC and meet fan, pump and compressor applications requirements.

A standby mode helps to decrease system power consumption when the motor is stopped. The high-voltage level shifting function with boot strap diode function is integrated into the gate driver IC. The device also contains the six low-loss 500V power FET or 650V CoolMOS which form the three phase inverter circuit.

1.1 IMM100T - Motion Control Engine

iMOTION™ IMM100T is the latest generation inverter including controller designed as a single package solution for inverterized motor control applications with or without power factor correction. The IMM100T series provides a built-in closed loop sensorless (or optionally sensor based) control algorithm using the unique flexible Motion Control Engine (MCE) for permanent magnet motors. Infineon's patented and field proven MCE implements field oriented control (FOC) using single or leg shunt current feedback and uses space vector PWM with sinusoidal signals to achieve highest energy efficiency. In addition to the motor control algorithm it also integrates multiple protection features like over- and under-voltage, over current, rotor lock etc. The IMM100T series takes advantage of a new hardware platform combining an ARM® Cortex® core with an innovative set of analog and motor control peripherals. The high-level of integration in terms of hardware and software results in a minimum number of external components required for the implementation of the inverter control.

The next generation of the MCE not only further improves the performance of the control algorithm but also adds functionality like sensor support for accurate rotor positioning, ready-to-use PFC algorithm as well as more and flexible and faster host interface options.

The IMM100T series is offered in several device variants ranging from single motor control to motor control plus PFC. All devices can be used in applications requiring functional safety according to IEC 60335 ('Class B').

This data sheet provides all electrical, mechanical, thermal and quality parameters. A more detailed description of the features and functionality can be found in the respective reference manual of the MCE software.

There are multiple versions of the MCE software offered from Infineon and made available via download from the Infineon web site. By using a special secure boot algorithm it is assured that the MCE software versions can only be installed onto the matching hardware derivative, i.e. IMM100T variants for which the software has been tested and released. Infineon provides the tools to program these software images.

1.2 Gate Driver

The gate driver is designed to work with MCE within an integrated power module. It has integrated boot strap bootFET structure, only external bootstrap capacitors are needed outside the module. The gate driver includes an under voltage protection and a fault reporting system. The gate driver is based on 600V High-Voltage Junction Isolation technology.

1.3 Switches

The IMM100T modules are available in three different power stage options

- 6 Ohm 500V Trench MOSFETs in versions IMM101T-015 and IMM102T-015
- 1.4 Ohm 650V CoolMOS™ in versions IMM101T-046 and IMM102T-046 (600V maximum voltage is defined by gate driver technology)

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Overview

• 0.95 Ohm 650V CoolMOS™ in versions IMM101T-056 and IMM102T-056 (600V maximum voltage is defined by gate driver technology)

1.4 Application Diagrams

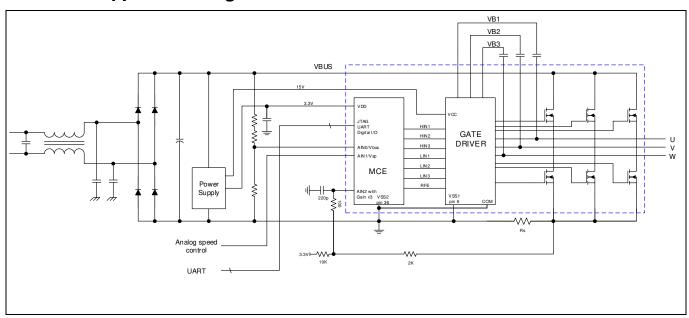


Figure 1 Application Block Diagram using IMM101T - Single Shunt Configuration

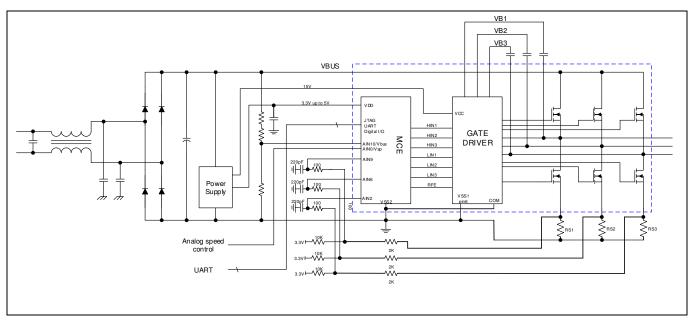


Figure 2 Application Block Diagram using IMM101T – Leg Shunts Configuration

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1.5 IMM100T Application Use Cases

This chapter provides more details about most common application use cases for IMM100 series' devices, including necessary passive components and pin connections. For full information about each pin functionality, refer to Table1.

1.5.1 Sensorless Single-Shunt

The sensorless single-shunt use case shown below is a most common application use case for IMM100 devices, alowing lowest BOM cost and highest number of available programmable pins for system-level functions.

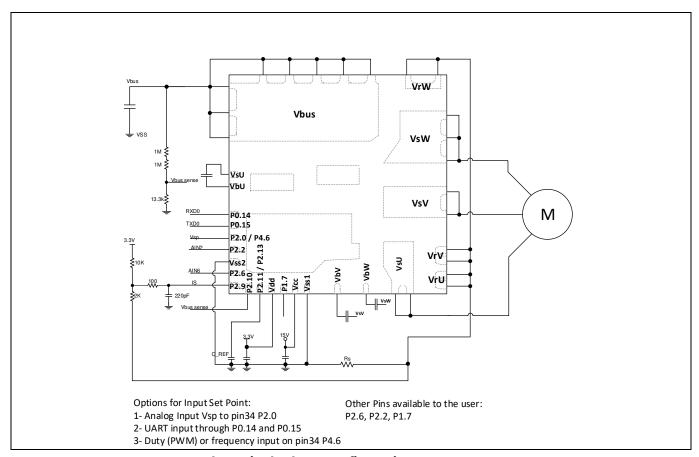


Figure 3 IMM101T Sensorless, single shunt configuration

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Overview

1.5.2 Sensorless Leg Shunts

The sensorless leg shunts configuration may be used in applications where only very low acoustic noise is requrired.

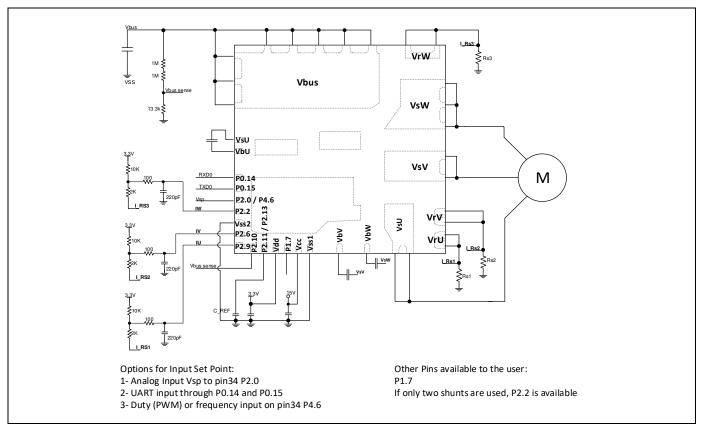


Figure 4 IMM101T Sensorless, three leg shunts configuration

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Overview

1.5.3 Configuration with 2 Hall Sensors

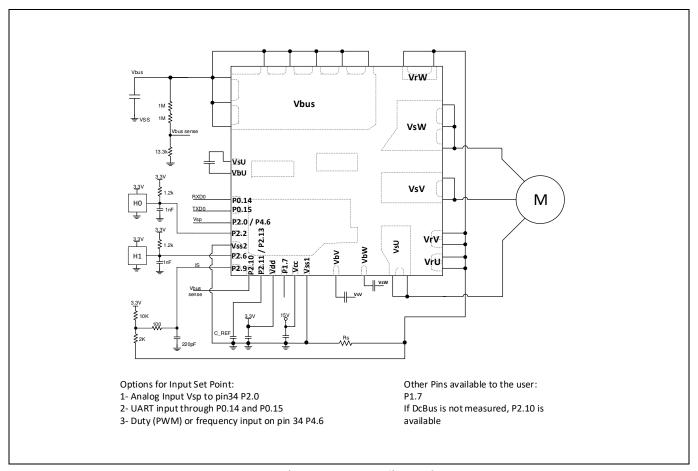


Figure 5 IMM101T Two Hall sensors, single shunt configuration

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Overview

1.5.4 Sensorless single-shunt with boost PFC

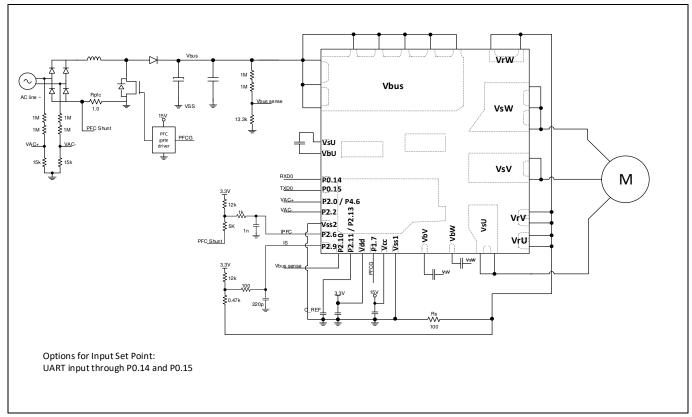


Figure 6 IMM102T Sensorless Single shunt with Boost PFC function

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2 Pinout - IMM100T series

Table 1 Pinout description IMM101T series – single motor control – typical configuration

Pin	Name	Туре	Description
1	Vbus scaled	I	Vbus scaled ADC input
2	CREF	I/O	Analog Overcurrent Comparator threshold DAC
3	V_{DD}	Р	Digital V _{DD} input [3.3V – 5.0V]
4	P1.7	I/O	Digital Input Analog and Digital Output
5	Vcc	Р	15V gate driver power supply input
6	V _{ss} 1	Р	Gate Driver Power ground, connect externally via PCB to pin 36
7	VbV	Р	V phase bootstrap capacitor positive
8	VbW	Р	W phase bootstrap capacitor positive
9,10	VsU	Р	U phase output
11,12	VrU	Р	Leg U return – Low-Side MOS source
13,14	VrV	Р	Leg V return – Low-Side MOS source
15,16,40	VsV	Р	V phase output and V phase bootstrap capacitor negative
17,18,19	VsW	Р	W phase output and W phase bootstrap capacitor negative
20,21	VrW	Р	Leg W return – Low-Side MOS source
22~29	Vbus	Р	DC bus voltage
30, 39	VsU	Р	U phase bootstrap capacitor negative
31	VbU	Р	U phase bootstrap capacitor positive
32	RX0	I	Serial Port Receive input
33	TX0	0	Serial Port transmit output
34	Vsp/AIN 0	I	Analog Voltage Set Point Input
35	IW (or H0)/AIN 2	I	Analog Current sense input phase W or Hall0 input
36,41	V _{ss} 2	Р	Signal ground Connect externally via PCB to pin 6
37	IV (or H1)/AIN 6	I	Analog Current sense input phase V or Hall1 input
38	ISS or IU	I	Analog Current sense input phase U or single Shunt

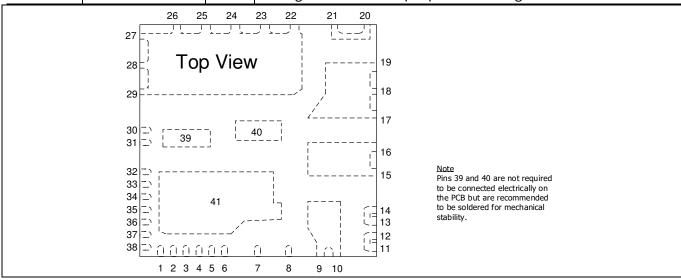


Figure 7 IMM100T series pinout

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Pinout - IMM100T series

Table 2 Pinout description IMM102T series – single motor + PFC – typical configuration

Pin	Name	Туре	Description
1	Vbus scaled	I	Vbus scaled ADC input
2	CREF	I/O	Analog Overcurrent Comparator t hreshold DAC
3	V_{DD}	Р	Digital V _{DD} input [3.3V – 5.0V]
4	PFCG	0	PWM Output to PFC gate driver
5	Vcc	Р	15V gate driver power supply input
6	V _{ss} 1	Р	Gate Driver Power ground, connect externally via PCB to pin 36
7	VbV	Р	V phase bootstrap capacitor positive
8	VbW	Р	W phase bootstrap capacitor positive
9,10	VsU	Р	U phase output
11,12	VrU	Р	Leg U return – Low-Side MOS source
13,14	VrV	Р	Leg V return – Low-Side MOS source
15,16,40	VsV	Р	V phase output and V phase bootstrap capacitor negative
17,18,19	VsW	Р	W phase output and W phase bootstrap capacitor negative
20,21	VrW	Р	Leg W return – Low-Side MOS source
22~29	Vbus	Р	DC bus voltage
30, 39	VsU	Р	U phase bootstrap capacitor negative
31	VbU	Р	U phase bootstrap capacitor positive
32	RX0	I	Serial Port Receive input
33	TX0	0	Serial Port transmit output
34	Vac+	I	Vac input ac+ voltage sensing through resistor external divider
35	Vac-	I	Vac input ac- voltage sensing through resistor external divider
36,41	V _{ss} 2	Р	Signal ground Connect externally via PCB to pin 6
37	IPFC	I	Analog Current sense input PFC
38	ISS	I	Analog Current sense input single Shunt

Note: IMM101T and IMM102T share same package footprint.

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3 Gate Driver Function

3.1 Features and Protections

The 3-phase high-voltage gate driver function is integrated in IMM100 series product. The driver output impedance is designed to meet an optimal dv/dt for EMI and switching loss trade offs. It is designed for 5-6 V/nsec at a rated current condition. The driver employs the anti-shoot-through protection, the integrated bootstrap function for high-side floating supplies, the low standby power and the undervoltage lockout protection function for VCC and high-side VBS supplies. The under voltage lockout for Vcc is reported as latched fault at pin RFE. The ITRIP comparator between COM and V_{SS} pin is disabled in IMM100. The gate driver block diagram is shown in Figure 10.

3.1.1 Integrated Bootstrap Functionality

The IMM100 series embeds an integrated bootstrap FET (BootFet) that allows an alternative drive of the bootstrap supply for a wide range of applications. Each bootstrap FET is connected between the respective floating supply VB (e.g. VBU, VBV and VBW, see page 15) and V_{cc} :

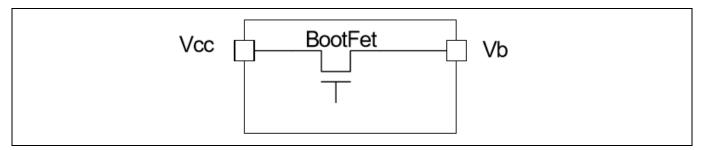


Figure 8 Simplified BootFET connection

The bootstrap FET is suitable for most PWM modulation schemes, including trapezoidal control, and can be used either in parallel with the external bootstrap network (diode+ resistor) or as a replacement of it. The use of the integrated bootstrap FET as a replacement of the external bootstrap network may have some limitations at a very high PWM duty cycle due to the bootstrap FET equivalent resistance (RBS, see page 17).

The integrated bootstrap FET is turned on during the time when LO is 'high' (e.g. LOU, LOV, LOW, see page 15), and it has a limited source current due to R_{BS} . The V_{BS} voltage will be charged each cycle depending on the on-time of LO and the value of the C_{BS} capacitor, the drain-source drop of the MOSFET, and the low-side free-wheeling diode drop.

The bootstrap FET follows the state of low-side output stage, the bootstrap FET is ON when LO is high, unless the V_B voltage is higher than approximately V_{CC} . In that case, the bootstrap FET is designed to remain off until V_B returns below that threshold; this concept is illustrated in Figure 9.

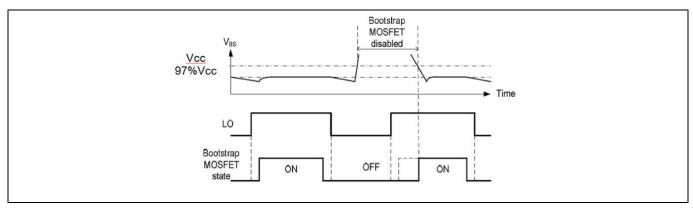


Figure 9 Bootstrap FET timing diagram

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Gate Driver Function

3.1.2 Undervoltage Lockout Protection

This IC provides under-voltage lockout protection on both the V_{CC} (logic and low-side circuitry) power supply and the V_{BS} (highside circuitry) power supply. Figure 10 is used to illustrate this concept; V_{CC} (or V_{BS}) is plotted over time and as the waveform crosses the UVLO threshold ($V_{CCUV+/-}$ or $V_{BSUV+/-}$) the under-voltage protection is enabled or disabled.

Upon power-up, should the V_{CC} voltage fail to reach the V_{CCUV^+} threshold, the IC will not turn-on. Additionally, if the V_{CC} voltage decreases below the V_{CCUV^-} threshold during operation, the under-voltage lockout circuitry will recognize a fault condition and shutdown the high and low-side gate drive outputs.

Upon power-up, should the V_{BS} voltage fail to reach the $V_{BSUV^{\perp}}$ threshold, the IC will not turn-on. Additionally, if the V_{BS} voltage decreases below the $V_{BSUV^{\perp}}$ threshold during operation, the under-voltage lockout circuitry will recognize a fault condition, and shutdown the high-side gate drive outputs of the IC.

The UVLO protection ensures that the IC drives the external power devices only when the gate supply voltage is sufficient to fully enhance the power devices. Without this feature, the gates of the external power switch could be driven with a low voltage, resulting in the power switch conducting current while the channel impedance is high; this could result in very high conduction losses within the power device and could lead to power device failure. (V_{CCUV+/-} and V_{BSUV+/-}, see page 25)

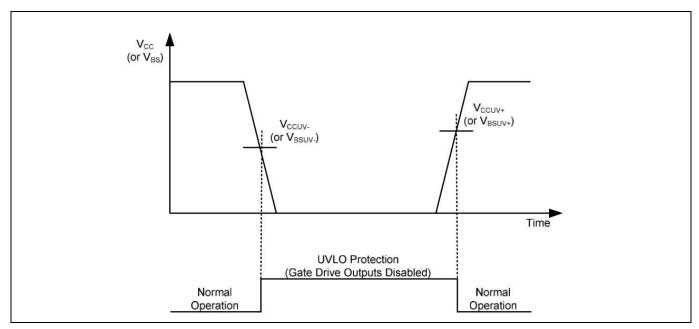


Figure 10 UVLO protection

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3.2 Block Diagram

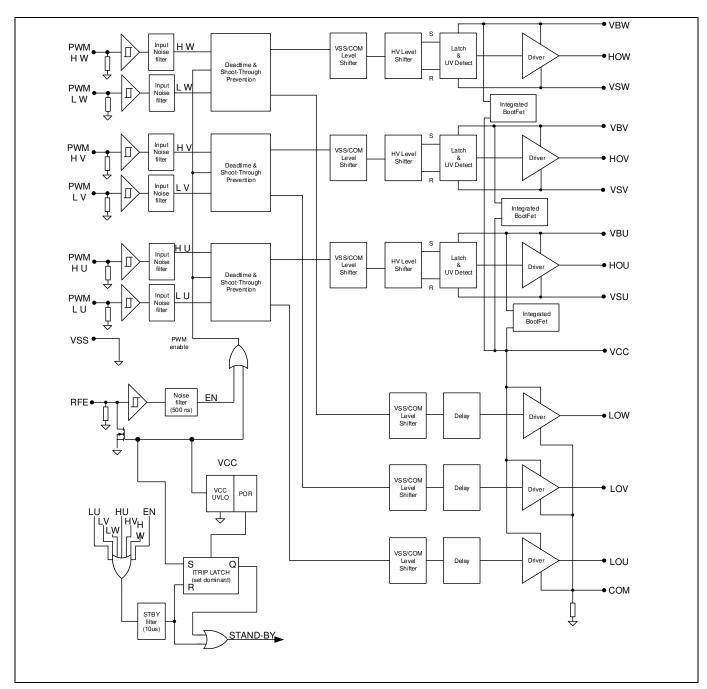


Figure 11 Block diagram of gate driver function

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4 DC Characteristics

4.1 Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the module may occur. These are not tested at manufacturing. All voltage parameters are absolute voltages referenced to V_{SS} unless otherwise stated in Table 2.

Table 2 Absolute Maximum Rating

Symbol	Description		Min	Max	Unit
BV _{DSS}	MOSFET Blocking Voltage	-015M		500	V
		-046M and -056M		650	V
I _o @T _c =25°C	DC Output Current per MOSFET	-015M		1	Α
		-046M and -056M		4	Α
I _{OP}	Pulsed Output Current 1)	-015M		6	Α
		-046M		8.2	Α
		-056M		11	Α
P _D @T _C =25°C	Maximum Power Dissipation per	-015M		11	W
	MOSFET 2)	-046M		28.4	W
		-056M		36.7	W
$V_{\text{SU,V,W}}$	Gate Driver High-Side Floating Su	pply Offset Voltage	V _{B U,V,W} -20	$V_{B U,V,W} + 0.3$	V
$V_{BU,V,W}$	Gate Driver High-Side Floating Ra	-0.3	600	V	
	Gate Driver High-Side Floating Ra 056	-0.3	600	V	
V _{cc}	Gate Driver Low-Side Supply Volt	-0.3	20	V	
BV _{MODULE}	Power Module Max Voltage -015M	_		500	V
	Power Module Max Voltage -046M	I -056M		600	V
V_{DD}	Digital IC Supply Voltage		-0.3	6	V
V _{ID}	Digital and Analog Pin Voltage		-0.3	V _{DD} +0.3	V
T _J	Operating Junction Temperature Controller technology	- defined by	-40	115	°C
T _L	Lead Temperature (Soldering, 30	seconds)		260	°C
T _s	Storage Temperature		-40	125	°C
V _{ISO}	Isolation Voltage (1min)			1500	V_{RMS}
I _{IN}	Input current on any controller pi condition	n during overload	-10	10	mA
ΣI_{IN}	Absolute sum of all controller inp overload condition	ut currents during	-50	50	mA

¹⁾ Pulse Width=100 μ s, T_c=25°C, Duty=1%.

Note: Characterized, not tested at manufacturing.

²⁾ Single MOSFET in TO220 package at Tcase = 25°C

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4.2 Recommended Operating Conditions

All voltage parameters are referenced to V_{ss}.

Table 3 Recommended Operating Conditions

Symbol	Description	Min	Тур	Max	Unit
V_{DCP}	Positive DC Bus Input Voltage - 015		380	400	٧
	Positive DC Bus Input Voltage – 046 056		400	480	٧
$V_{BU,V,W}$	Gate Driver High-Side Floating Supply Voltage	V _s +12		V _s +18	٧
V _{cc}	Gate Driver Low-Side Supply Voltage	13.5	15.0	16.5	٧
V _{DD}	Digital IC Supply Voltage (3.3 V +/- 10%)	2.97	3.3	3.63	٧
V _{DD}	Digital IC Supply Voltage (5.0V +/- 10%)	4.5	5.0	5.5	V
MCLK	Master clock frequency		48.0		MHz
PCLK	Peripheral clock frequency		96.0		MHz
l _{ov}	Input current on any port pin during overload condition	-5		5	mA
I _{ovs}	Absolute sum of all input circuit currents during overload condition			25	mA

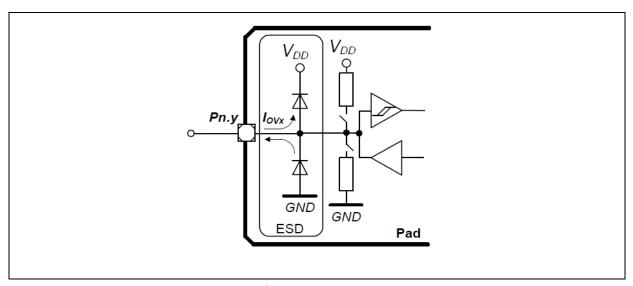


Figure 12 Input Overload Current via ESD structures

4.3 Static Electrical Characteristic

V_{cc}=15 V, T_A=25°C unless otherwhise specified.

Table 4 Static Electrical Characteristic

Symbol	Description		Min	Тур	Max	Units
V _{DS} =500/650V	Leakage Current of High-Side FETs in Parallel	-015M		1		μΑ
		-046M		1		
		-056M		1		
I _{LKL} @T _J =25°C, V _{DS} =500/650V	Leakage Current of Low-Side FETs with	-015M		4		μΑ
		-046M		4		
		-056M		4		

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DC Characteristics

Symbol	Description		Min	Тур	Max	Units
	Gate Drive IC in Parallel					
$R_{DS(ON)}$	Drain to Source ON	-015M		4.8	6	Ω
@T _J =25°C,	@T」=25°C, Resistance	-046M		1.26	1.4	
V _{GS} =10V, I _D =1.5A		-056M		0.855	0.95	
I _{DSS}	Zero Gate Voltage	-015M			1	μΑ
@T _J =25°C, Drain Current V _{DS} =500/650 V, V _{GS} =0 V	Drain Current	-046M			1	
		-056M			1	
V _{SD} @T _J =25 °C,	MOSFET Diode Forward Voltage Drop	-015M		0.8		V
V_{GS} =0 V, I_F =0.5		-046M		0.9		
A (-015M), I _F =1.5 A (- 046M), I _F =2.2 A (-056M)		-056M		0.9		
R _{BS}	Bootstrap FET	-015M		200		Ω
	Resistance	-046M		200		
		-056M		200		

Note: All values obtained during characterization, not tested at munfacturing.

4.4 Dynamic Electric Characterisitic

 V_{CC} =15 V, T_{A} =25°C, all voltage parameters are referenced to V_{SS} unless otherwise specified.

Table 5 Dynamic Electric Characteristic

Symbol	Description		Min	Тур	Max	Units
E _{on} @Τ _J =25 °C,	Switching Energy,	-015M		27.2		μJ
$V^{+}=300 \text{ V}, I_{D}=0.5$	Turn On Condition	-046M		36.6		
Α		-056M		44.4		
E _{OFF} @T _J =25 °C,	Switching Energy,	-015M		2.00		μJ
$V^{+}=300 \text{ V}, I_{D}=0.5$	Turn Off Condition	-046M		1.97		
Α		-056M		2.53		
E _{REC} @T _J =25 °C,	Switching Energy, Diode Reverse Recovery	-015M		10.8		μJ
$V^{+}=300 \text{ V, } I_{D}=0.5$		-046M		8.43		
Α		-056M		9.88		
E _{on} @T _J =115 °C,	Switching Energy,	-015M		31.8		μJ
$V^{+}=300 \text{ V, } I_{D}=0.5$	Turn On Condition	-046M		49.7		
Α		-056M		59.7		
E _{OFF} @T _J =115	Switching Energy,	-015M		1.96		μJ
°C, V ⁺ =300 V, I _D =0.5 A	Turn Off Condition	-046M		1.81		
		-056M		2.27		
		-015M		12.6		μJ

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DC Characteristics

Symbol Description Min		Description		Тур	Max	Units
E _{REC} @T _J =115	Switching Energy,	-046M		7.94		
°C, V ⁺ =300 V, I _D =0.5 A	Diode Reverse Recovery	-056M		9.91		

Note: All values obtained during characterization, not tested at munfacturing.

4.5 MOSFET Avalanche Characteristics

Table 6 MOSFET Avalanche Characteristic

Symbol	Description		Min	Тур	Max	Units
EAS, V ⁺ =100 V, I _D =1.7 A	Single Pulse Avalanche Energy	-015M			49	mJ
EAS, V ⁺ =50 V, I _D =0.6 A		-046M			26	
EAS, $V^+=50 V$, $I_D=1 A$		-056M			50	

Note: All values obtained during characterization, not tested at munfacturing.

4.6 Thermal Characteristics

Table 7 Thermal Characteristics

Symbol	Description	Min	Тур	Max	Units
$R_{th(J-amb)}$	Total Thermal Resistance Junction to Ambient		27.7		°C/W

Note: All values obtained during characterization, not tested at munfacturing.

The previous value of $R_{th(J-amb)}$ has been obtained under the following testing condition: T_{amb} =25°C, $T_{hotspot}$ =51.6°C and a dissipated power of 1W. A FR4 PCB with 2oz copper has been used and the PCB layout is shown in Figure 13.

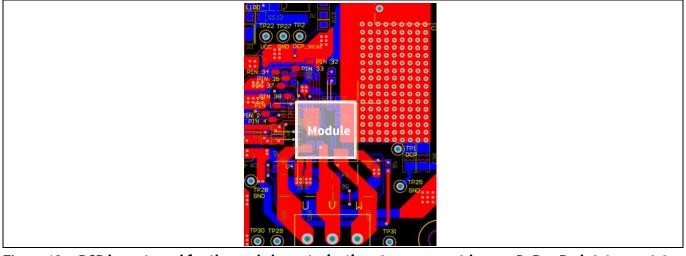


Figure 13 PCB layout used for thermal characterization: 2oz copper, 2 layers. DcBus Pad: 3,0 cm x 1,8 cm on both layers with 144 vias.





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4.7 Thermal Characterization

DC Characteristics

Figure 14, 15, 16, 17, 18, 19 show the thermal characterizations of the three part numbers. The tests reported in Figure 14, 15, 16 have been performed under the following conditions: T_{amb}=25°C, different phase current values until the case reaches 105°C, two PWM frequencies (6 and 16kHz) and two different modulation types (3-phase modulation and 2-phase flat bottom modulation). The tests reported in Figure 17, 18, 19 have been performed under the following conditions: T_{amb}=60°C, different phase current values until the case reaches 105°C, two PWM frequencies (6 and 16kHz) and two different modulation type (3-phase modulation and 2-phase flat bottom modulation). 2-ph flat bottom modulation allows the reduction of the switching losses compared with 3-phase SVPWM (symmetrical placement of zero vectors). For the test with T_{amb}=60°C, the 3-phase modulation has not been used. For all the tests, the phase current has been limited to 600 mArms in order to avoid damage to the motor used for the tests. A FR4 PCB with 2oz copper has been used and the PCB layout is shown in Figure 13.

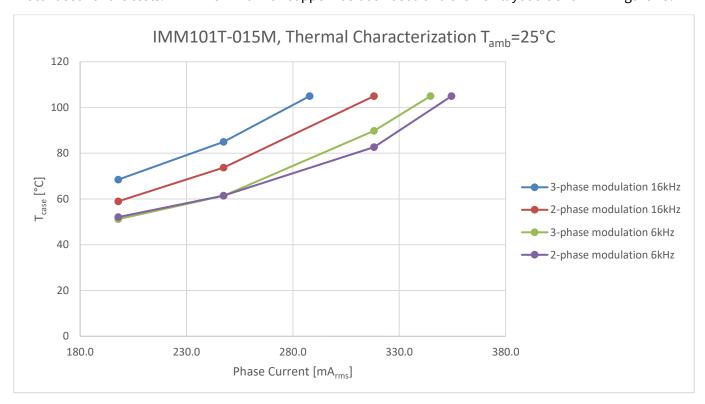


Figure 14 IMM101T-015M Thermal Characterization, T_{amb}=25°C, different phase current values until the case reaches 105°C, FR4 PCB with 2oz copper

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DC Characteristics

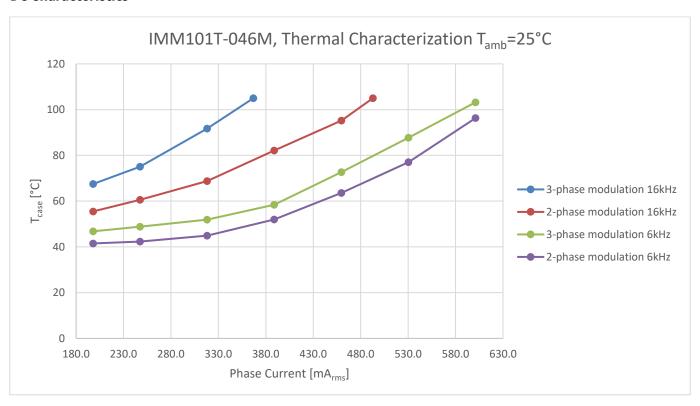


Figure 15 IMM101T-046M Thermal Characterization, T_{amb}=25°C, different phase current values until the case reaches 105°C, FR4 PCB with 2oz copper

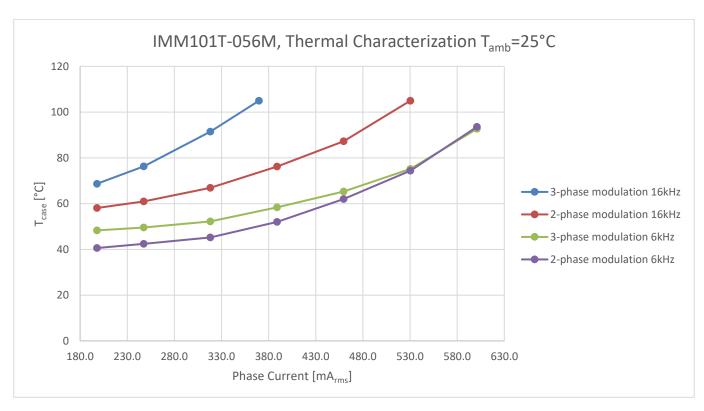


Figure 16 IMM101T-056M Thermal Characterization, T_{amb}=25°C, different phase current values until the case reaches 105°C, FR4 PCB with 2oz copper

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DC Characteristics

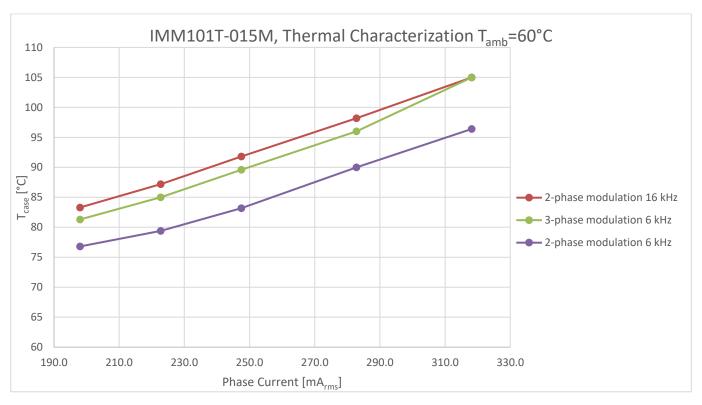


Figure 17 IMM101T-015M Thermal Characterization, T_{amb}=60°C, different phase current values until the case reaches 105°C, FR4 PCB with 2oz copper

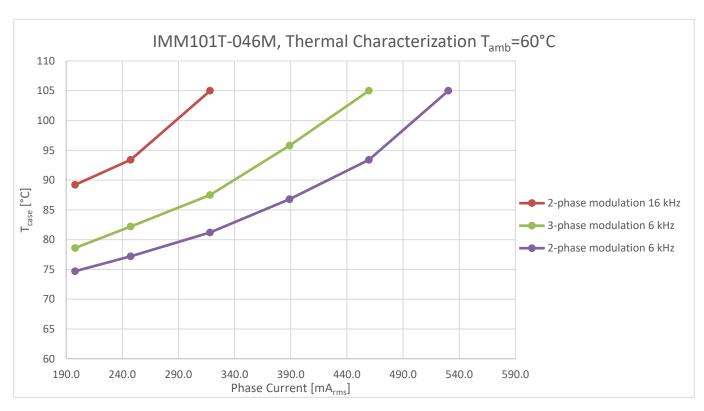


Figure 18 IMM101T-046M Thermal Characterization, T_{amb}=60°C, different phase current values until the case reaches 105°C, FR4 PCB with 2oz copper

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DC Characteristics

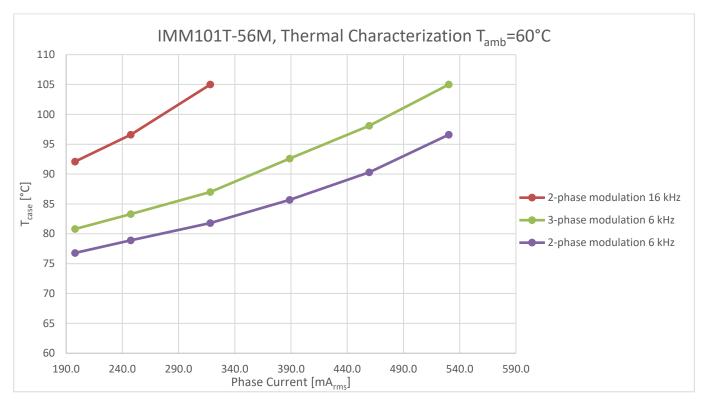


Figure 19 IMM101T-056M Thermal Characterization, T_{amb}=60°C, different phase current values until the case reaches 105°C, FR4 PCB with 2oz copper

Note: Characterized, not tested at manufacturing.

4.8 Power Consumption IMM100T series

 V_{CC} =15V, V_{DD} =5V, V_{BUS} = 300V, Ta = 25 °C, unless specified otherwise.

Note: These parameters are not subject to production test, but verified by design and/or characterization.

Table 8 Power Consumption – IMM100T series

Symbol	Parameter	Min	Тур	Max	Unit	Condition
P _{MOTOR}	Power Consumption – motor active and PFC not active		50	100	mW	
P _{MOTOR+PFC}	Power Consumption – motor and PFC active		70	100	mW	IMM102T only
I _{DDPDS}	Deep Sleep mode controller current		0.27		mA	
t _{SSA}	Controller Wake-up time from Sleep to Active mode		6		Clock cycles	
t _{DSA}	Controller Wake-up time from Deep Sleep to Active mode		290		μs	

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DC Characteristics

4.9 Flash Memory Parameters

Note: These parameters are not subject to production test, but verified by design and/or characterization.

Table 9

Symbol	Parameter	Min	Тур	Max	Unit	Condition
t _{RET}	Data Retention Time	10			years	Max. 100 erase / program cycle
N _{ECYC}	Erase Cycles			5 x 10 ⁴	cycles	Sum of pages and sector erase cycles
N _{TECYC}	Total Erase Cycles			2 x 10 ⁶	cycles	

4.10 Digital I/O DC Characteristics

 V_{DD} =3.3V, Ta = 25 °C, all voltage parameters are referenced to V_{SS} unless specified otherwise.

Note: These parameters are not subject to production test, but verified by design and/or characterization.

Table 10 Digital I/O Charasteristics

Symbol	Parameter	Min	Тур	Max	Unit	Condition
V _{ILPS}	Input Low-Voltage on port pins			0.19 x	V	
	with std Hysteresis			V_{DD}		
V _{IHPS}	Input High-Voltage on port pins	0.7 x			V	
	with std Hysteresis	V_{DD}				
V _{ILPL}	Input Low-Voltage on port pins			0.08 x	V	
	with large Hysteresis			V_{DD}		
V _{IHPL}	Input High-Voltage on port pins	0.85 x			V	
	with Large Hysteresis	V_{DD}				
V _{OLP}	Output Low-Voltage on port pins			0.4	V	I _{OL} = 3.5 mA
	(with standard pads)					
V _{OLP1}	Output Low-Voltage on high-			0.32	V	I _{OL} = 10 mA
	current pads					
V_{OHP}	Output High-Voltage on port pins	V_{DD} -0.4			٧	$I_{OH} = -2.5 \text{ mA}$
	(with standard pads)					
V_{OHP1}	Output High-Voltage on	V _{DD} –			V	$I_{OH} = -6 \text{ mA}$
	high-current pads	0.32				
IL	Input leakage current	-1		+1	μΑ	$V_0 = 3.3 \text{V or } 0 \text{V}$
I_{OL}	Low-Level output current			5	mA	$V_0 = 0.4V$
				3	ША	
I_{OH}	High-Level output current			-7	mA	$V_0 = 2.4V$
				= 1	ША	
$t_{HCPR}t_{HCPF}$	Rise/fall time on High-Current			12	ns	50 pF
	Pad			12	113	30 pi
$t_R t_F$	Rise/fall time on std Pad			15	ns	50 pF

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DC Characteristics

Symbol	Parameter	Min	Тур	Max	Unit	Condition
C _{IO}	Pin capacitance (digital inputs/outputs)			10	pF	
I _{PUP}	Pull-up current on port pins			-50	μΑ	V _{IH} ,min
	Pull-up current on port pins	-65			μΑ	V _{IL} ,max
I _{PDP}	Pull-down current on port pins			30	μΑ	V₁∟,max
	Pull-down current on port pins	60			μΑ	V₁ӊ,min
V_{PO}	Voltage on any pin during V _{DD} power off			0.3	V	

4.11 Analog I/O DC Characteristics

 V_{DD} =3.3V, Ta = 25 °C, all voltage parameters are referenced to V_{SS} unless specified otherwise.

Note: These parameters are not subject to production test, but verified by design and/or characterization.

Table 11 Analog I/O Charasteristics

Symbol	Parameter	Min	Тур	Max	Unit	Condition
	Switched capacitance of analog		1.2	2	pF	Gain 1, 3
C_{IN}	inputs		4.5	6	pF	Gain 6, 12
ADC_GAIN	ADC Configurable Gain		1 - 3 - 6 - 12			
C _{AINT}	Total capacitance of an analog input			10	pF	
C _{AREFT}	Total capacitance of reference input			10	pF	

4.12 Under Voltage Lockout DC characteristics

Ta = 25 °C, all voltage parameters are referenced to V_{ss} unless specified otherwise.

Note: These parameters are not subject to production test, but verified by design and/or characterization.

Table 12 Undervoltage Lockout DC Charasteristics

Symbol	Parameter	Min	Тур	Max	Unit	Condition
V _{DDPBO}	V _{DD} Brownout reset voltage	1.55	1.62	1.75	V	
V_{DDPA}	V _{DD} voltage to ensure defined pad states		1.0		V	
t _{ssw}	Start-up time from power-on reset		260		μs	
t _{BMI}	BMI program time		8.25		ms	
$V_{\text{CCUV+}}$ $V_{\text{BSUV+}}$	V _{CC} and V _{BS} supply undervoltage positive going threshold - gate driver	8.0	8.9	9.8	V	
V _{CCUV} -	V _{CC} and V _{BS} supply undervoltage negative going threshold - gate driver	7.4	8.2	9.0	V	





DC Characteristics

V _{CCUVH}	V _{cc} and V _{BS} supply under voltage	 0.7	 ٧	
$V_{\sf BSUVH}$	hysteresis – gate driver			

4.13 Analog to Digital Converter – IMM100T series

The following table shows the Analog to Digital Converter (ADC) characteristics. This specification applies to all analog input as given in the pin configuration list.

Note: These parameters are not subject to production test, but verified by design and/or characterization.

Table 13 ADC Characteristics – IMM100T series

Symbol	Parameter	Min	Тур	Max	Unit	Condition
V _{AIN}	Analog input voltage range	Vss - 0.05		V _{DD} + 0.05	V	
t _{sample}	Sample Time		200		ns	
EN _{RMS}	RMS noise		1.5		LSB 12	
EA _{DNL}	DNL error		+/- 2.0		LSB 12	
EA _{INL}	INL error		+/- 4.0		LSB 12	
EA _{GAIN}	Gain error with external reference		+/- 0.5		%	
EA _{OFF}	Offset error		+/- 8.0		mV	

4.14 Temperature Sensor Characteristic

IMM101T and IMM102T have an internal temperature sensor that is used by MCE to linearly derate the power consumption and protect the power section. The linear power derating function with temperature shutdown is defined by parameters programmed by the user.

The power dissipation must be limited so that the average controller junction temperature does not exceed 115 °C.

Note: 7

Temperature sensor characteristic is not subject to production test, but verified by design and/or characterization.

Table 14 Temperature Sensor Characteristics

Symbol	Parameter	Min	Тур	Max	Unit	Condition
t _M	Measurement time ²⁾			10	ms	
T_SR	Temperature sensor range	-40		115	°C	
T _{TSAL}	Sensor Accuracy ¹⁾	-6		6	°C	T _J > 20°C
		-10		10	°C	0°C ≤ T _J ≤ 20°C
			+/-8		°C	T _J < 0°C

- 1) The temperature sensor accuracy is independent of the supply voltage.
- 2) The temperature of the different parts of the IMM100 is strongly impacted by the thermal design of the application and may be different from the temperature sensor reading. It is the designers' responsibility to always ensure that the maximum ratings given in this datasheet are never exceeded.

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5 AC Characteristics

5.1 Internal Oscillator AC Characteristics

 V_{DD} =3.3V, Ta = 25 °C unless specified otherwise.

Note: These parameters are not subject to production test, but verified by design and/or characterization.

Table 15 96MHz DCO1 Oscillator characteristics

Symbol	Parameter	Min	Тур	Max	Unit	Condition
$f_{NOM}CC$	Nominal Frequency	-	96	-	MHz	Under nominal conditions after trimming
$\Delta f_{LTX} CC$	Accuracy with adjustment based on XTAL as reference	-0.3	-	+0.3	%	With respect to f_{NOM} (typ), Ta = -40 °C ~ 105 °C
$\Delta f_{LTTS} CC$	C Accuracy with adjustment algorithm ¹⁾ based on temperature sensor	-0.6	-	+0.6	%	With respect to f_{NOM} (typ), Ta = 0 °C ~ 105 °C
		-1.9	-	+1.0	%	With respect to f_{NOM} (typ), Ta = -25 °C ~ 105 °C
		-2.6	-	+1.3	%	With respect to f_{NOM} (typ), Ta = -40 °C ~ 105 °C
$\Delta f_{LT} CC$	Accuracy	-1.7	-	+3.4	%	With respect to f_{NOM} (typ), Ta = 0 °C ~ 85 °C
		-3.9	-	+4.0	%	With respect to f_{NOM} (typ), Ta = -40 °C ~ 105 °C

¹⁾ MCE version newer or equal to V1.03.00, clock adjustment algorithm for improved accuracy enable.

Table 16 32kHz DCO2 Oscillator characteristics

Symbol	Parameter	Min	Тур	Max	Unit	Condition
f _{NOM} CC	Nominal Frequency	32.5	32.75	33	MHz	Under nominal conditions ¹⁾ after trimming
$\Delta f_{\rm ST}$ CC	Short term frequency deviation (over VDD)	-1	-	+1	%	With respect to f_{NOM} (typ), Ta = 25°C
$\Delta f_{LT} CC$	Accuracy	-1.7	-	+3.4	%	With respect to f_{NOM} (typ), Ta = 0 °C ~ 85 °C
		-3.9	-	+4.0	%	With respect to f_{NOM} (typ), Ta = -40 °C ~ 105 °C

¹⁾ The deviation is related to the factory trimmed frequency at nominal VDD and Ta=+25C°

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5.2 Power-Up and Supply Threshold Characteristics

The guard band between the lowest valid operating voltage and the brownout reset threshold provides a margin for noise immunity and hysteresis. The electrical parameters may be violated while V_{DD} is outside its operating range. The brownout detection triggers a reset within the defined range. The prewarning detection can be used to trigger an early warning and issue corrective and/or fail-safe actions in case of a critical supply voltage drop.

Note: These parameters are not subject to production test, but verified by design and/or characterization.

Note: Operating Conditions apply.

 V_{DD} =3.3V, Ta = 25 $^{\circ}$ C unless specified otherwise. C=100nF between V_{DD} and V_{SS} .

Table 17 Power-Up and Supply

Symbol	Parameter	Min	Тур	Max	Unit	Condition
t _{RAMPUP}	V _{DD} ramp-up time			10 ⁷	μs	
S _{VDDPOP}	V _{DD} slew rate			0.1	V/µs	Slope during normal operation
S _{VDDP10}				10	V/µs	Slope during fast transient within +/-10% of V _{DD}
$S_{VDDPrise}$				10	V/µs	Slope during power-on or restart after brownout event
$S_{VDDPfail}$				0.25	V/µs	Slope during supply falling out of the +/-10% limits

5.3 Motor Control Parameters – IMM100T series

Motion Control parameters that are defined in the iMOTION™ motion control engine (MCE) software are defined and explained in iMOTION™ reference Manual.

5.3.1 PWM Characteristics – IMM100T series

Table 18 PWM timing in IMM100T

Symbol	Parameter	Min	Тур	Max	Unit	Condition
f_{PWM}	PWM frequency	5	16	40	kHz	

5.3.2 Fault timing – IMM100T series

Table 19 Fault timing in IMM100T

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AC Characteristics

Symbol	Parameter	Min	Тур	Max	Unit	Condition
t _{FLTwidth}	Minimum pulse width of fault event to be acknowledged at input over current comparators	1.0			μs	
t _{trap}	reaction time to acknowledged overcurrent at input comparators – Fault to PWM disable propoagation time		1.3		μs	

5.4 Power Factor Correction (PFC) parameters – IMM102T

The PFC parameters only refer to the IMM102T with integrated PFC control algorithm and are defined and explained in iMOTION™ reference Manual.

5.4.1 Boost PFC characteristics – IMM102T

Table 20 PFC PWM timing in IMM102T

Symbol	Parameter	Min	Тур	Мах	Unit	Condition
f_{PFCPWM}	PFC PWM frequency		20	70	kHz	

5.5 Communication interface parameters – IMM100T series

The IMM100T series provides the following communication interfaces.

Note: These parameters are not subject to production test, but verified by design and/or characterization.

5.5.1 UART interface - IMM100T series

The UART interface is configured as given below.

Note: Operating Conditions apply.

Note: Each bit including start and stop bit is sampled three times at center of a bit at an interval of 1/16

 T_{BAUD} .

Table 21 UART timing in IMM100T - series

Symbol	Parameter	Min	Тур	Max	Unit	Condition
f _{UART}	UART baud rate	1200	57600		bps	
	UART mode		8-N-1			data-parity-stop bit
t _{UARTFIL}	UART sampling filter period		1/16		T _{BAUD} =1/f _{UART}	

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I/O Structure



6 I/O Structure

The following figure shows the I/O structure for all digital I/O pins.

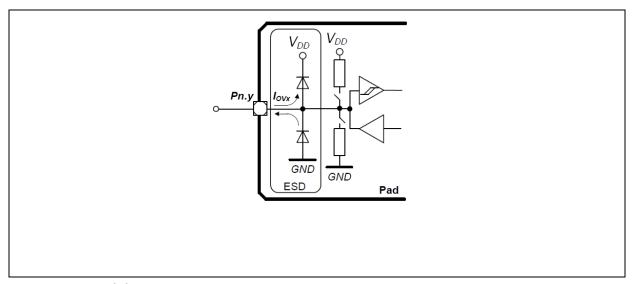


Figure 20 Digital I/O Structure

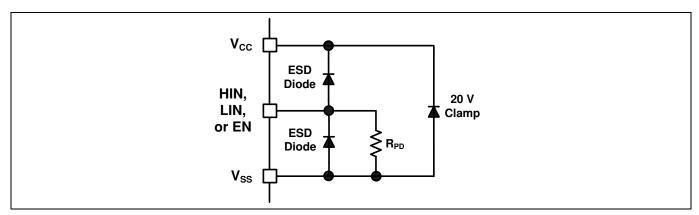


Figure 21 VCC pin I/O gate driver structure







Package Outline 7

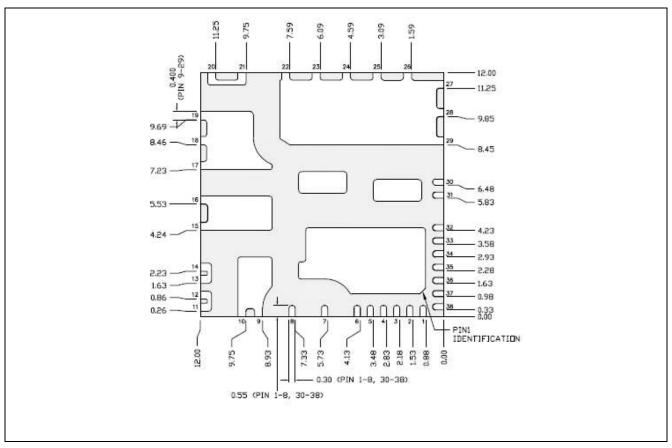


Figure 22 **Bottom View, Dimensions in mm**

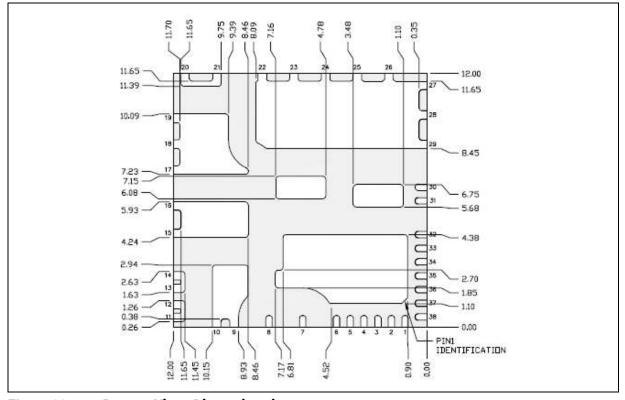


Figure 23 **Bottom View, Dimensions in mm**

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Package Outline

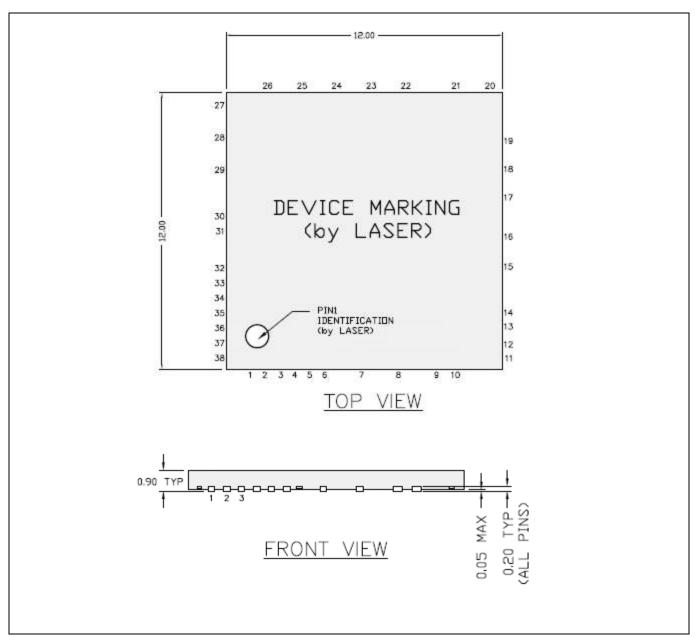


Figure 24 Top View and Dimensions

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Part Marking Information

8 Part Marking Information

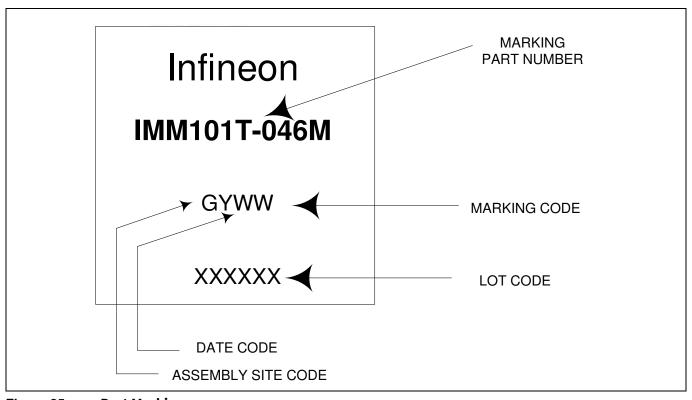


Figure 25 Part Marking

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9 Quality Declaration

Table 22 Quality Parameters

Qualification	on Level	Qualified for industrial applications according to the relevant tests of JEDEC47/20/22				
Moisture Sensitivity Level MSL3		MSL3				
		(per IPC/JEDEC J-STD-020C)				
ESD	Charged Device Model	Class C2B				
		(per ANSI/ESDA/JEDEC standard JS -002)				
	Human Body Model	Class C2				
		(per EIA/JEDEC standard EIA/JESD22-A114-F)				
RoHS Compliant		Yes				

Note:

Test condition for Temperature Cycling test is -40C to 125C.

Revision history

Document Version	Date of Release	Description of changes
v01_00	2019-04-10	Initial version
v01_01	2019-06-05	Typo Corrections
V01_02	2020-04-24	Revised oscillator accuracy specs. Changed max PWM frequency.

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Edition 2019-06-05 Published by Infineon Technologies AG 81726 Munich, Germany

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Document reference IFX-vqf1553180223116

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